

Zertifikat *Certificate*

Zertifikatsnummer Certificate No.:

PV 50625055 0004

Berichtsnummer Report No.:

CN24RW1D 007

Genehmigungsinhaber License Holder:

Changzhou EGing Photovoltaic
Technology Co., Ltd.
No.18 Jinwu Road, Yaotang Town
Jintan City
213213 Jiangsu
P.R. China

Fertigungsstätte Manufacturing Site:

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Technology Co., Ltd.
No.18 Jinwu Road, Yaotang Town
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213213 Jiangsu
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Prüfzeichen Test Mark:

Geprüft nach Tested according to:

IEC 61215-1:2021
IEC 61215-1-1:2021
IEC 61215-2:2021
IEC 61730-1:2023
IEC 61730-2:2023
EN IEC 61215-1:2021
EN IEC 61215-1-1:2021
EN IEC 61215-2:2021
EN IEC 61730-1:2018
EN IEC 61730-2:2018

Geräteidentifikation
Product Identification
Produkt: PV Module

Product:
Modell: Modelle sind auf nächste(r) Seite(n) gelistet

Type: Type designation(s) are listed on the next page(s)

Technische Daten: Class II acc. to IEC 61140

Technical Data: For other ratings, refer to the test report

Gültig bis: 2029-03-28

Date of expiry:
Gültig ab: 2025-05-30

Valid from:
Ausstellungsdatum: 2025-05-30

Date of issue:
Zertifizierungsstelle:
Certification body:

Angela Yao



Dem Zertifikat liegt unsere Prüf- und Zertifizierungsordnung zugrunde.
Das Produkt entspricht den o.g. Anforderungen, die Herstellung wird überwacht.
This certificate is based on our Testing and Certification Regulation. The product fulfills above mentioned requirements, the production is subject to surveillance.

TÜV Rheinland LGA Products GmbH, Tillystraße 2, 90431 Nürnberg
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Precisely Right.

Zertifikat *Certificate*

Zertifikatsnummer *Certificate No.:*

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Produkt *Product:* PV Module

Modell *Type:*

Bezeichnung *Designation:*

Same as Page 0001-0003

In addition:

Max. System Voltage: up to 1500 VDC (Voc at STC):

With cut of mono c-Si cells: (Under STC)

EG-xxxNT54-HRc/BF-DG (xxx=485-510, in steps of 5, 108 cells)

EG-xxxNT48-HRc/BF-DG (xxx=435-460, in steps of 5, 96 cells)

EG-xxxTB66-HRc/BF-DG (xxx=635-660, in steps of 5, 132 cells)

EG-xxxTB54-HRc/BF-DG (xxx=520-540, in steps of 5, 108 cells)

EG-xxxTB48-HRc/BF-DG (xxx=460-480, in steps of 5, 96 cells)

EG-xxxTB72-HL/BF-DG (xxx=605-630, in steps of 5, 144 cells)

EG-xxxTB60-HL/BF-DG (xxx=500-525, in steps of 5, 120 cells)

EG-xxxTB54-HL/BF-DG (xxx=450-475, in steps of 5, 108 cells)

With cut of mono c-Si cells: (Under BNPI)

EG-xxxNT54-HRc/BF-DG (xxx=537-565, 108 cells)

EG-xxxNT48-HRc/BF-DG (xxx=482-510, 96 cells)

EG-xxxTB66-HRc/BF-DG (xxx=695-722, 132 cells)

EG-xxxTB54-HRc/BF-DG (xxx=569-591, 108 cells)

EG-xxxTB48-HRc/BF-DG (xxx=503-525, 96 cells)

EG-xxxTB72-HL/BF-DG (xxx=662-690, 144 cells)

EG-xxxTB60-HL/BF-DG (xxx=547-575, 120 cells)

EG-xxxTB54-HL/BF-DG (xxx=493-520, 108 cells)

Power range extension for following models:

With cut of mono c-Si cells: (Under STC)

EG-xxxNT66-HU/BF-DG (xxx=720, 132 cells)

EG-xxxNT60-HU/BF-DG (xxx=655, 120 cells)

EG-xxxNT54-HRb/BF-DG (xxx=465-475, in steps of 5, 108 cells)

EG-xxxNT66-HRc/BF-DG (xxx=620-635, in steps of 5, 132 cells)

EG-xxxNT72-HL/BF-DG (xxx=600-610, in steps of 5, 144 cells)

EG-xxxNT60-HL/BF-DG (xxx=500-505, in steps of 5, 120 cells)

EG-xxxNT54-HL/BF-DG (xxx=450-455, in steps of 5, 108 cells)

With cut of mono c-Si cells: (Under BNPI)

EG-xxxNT66-HU/BF-DG (xxx=798, 132 cells)

EG-xxxNT60-HU/BF-DG (xxx=726, 120 cells)

EG-xxxNT54-HRb/BF-DG (xxx=515-526, 108 cells)

EG-xxxNT66-HRc/BF-DG (xxx=687-698, 132 cells)

EG-xxxNT72-HL/BF-DG (xxx=670-676, 144 cells)

EG-xxxNT60-HL/BF-DG (xxx=554-559, 120 cells)

EG-xxxNT54-HL/BF-DG (xxx=498-504, in steps of 5, 108 cells)

xxx represents output power in Wp

